

View Online at https://aerobasegroup.com/nsn/5961-00-710-9389

Inclosure Material:
Metal
Overall Length:
0.259 inches
Terminal Length:
0.750 inches
Overall Diameter:
0.362 inches
Component Name And Quantity:
1 semiconductor device diode and 1 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Semiconductor Material:
Silicon single transistor
Voltage Rating In Volts Per Characteristic:
45.0 collector to emitter voltage/static/base open single transistor
Current Rating Per Characteristic:
6.00 milliamperes source cutoff current horsepower metric single semiconductor device diode
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector absolute single transistor
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Terminal Type And Quantity:
4 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0